SN54AHCT573, SN74AHCT573 OCTAL TRANSPARENT D-TYPE LATCHES WITH 3-STATE OUTPUTS

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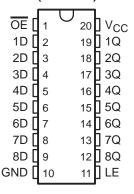
- **EPIC™** (Enhanced-Performance Implanted **CMOS) Process**
- Inputs Are TTL-Voltage Compatible
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- **Package Options Include Plastic** Small-Outline (DW), Shrink Small-Outline (DB), Thin Very Small-Outline (DGV), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) DIPs

description

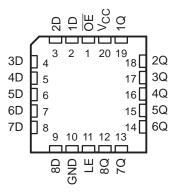
The 'AHCT573 devices are octal transparent D-type latches. When the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is low, the Q outputs are latched at the logic levels of the D inputs.

A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

SN54AHCT573...JORWPACKAGE SN74AHCT573...DB, DGV, DW, N, OR PW PACKAGE (TOP VIEW)



SN54AHCT573...FK PACKAGE (TOP VIEW)



To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

OE does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

The SN54AHCT573 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74AHCT573 is characterized for operation from -40°C to 85°C.

FUNCTION TABLE (each latch)

	INPUTS		OUTPUT
OE	LE	D	Q
L	Н	Н	Н
L	Н	L	L
L	L	Χ	Q ₀
Н	X	Χ	Z



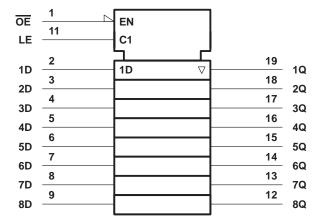
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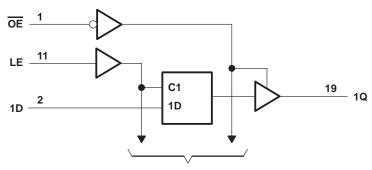
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logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



To Seven Other Channels

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V _{CC}		0.5 V to 7 V
Input voltage range, V _I (see Note 1)		–0.5 V to 7 V
Output voltage range, VO (see Note 1)		V to V_{CC} + 0.5 V
Input clamp current, $I_{IK}(V_I < 0)$		–20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CO}	3)	±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})		±25 mA
Continuous current through V _{CC} or GND		±75 mA
Package thermal impedance, θ _{JA} (see Note 2):	: DB package	70°C/W
	DGV package	92°C/W
	DW package	58°C/W
	N package	69°C/W
	PW package	83°C/W
Storage temperature range, T _{stg}		. −65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

^{2.} The package thermal impedance is calculated in accordance with JESD 51.



NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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recommended operating conditions (see Note 3)

		SN54AH	SN54AHCT573		SN74AHCT573		
		MIN	MAX	MIN	MAX	UNIT	
Vcc	Supply voltage	4.5	5.5	4.5	5.5	V	
VIH	High-level input voltage	2		2		V	
VIL	Low-level input voltage		0.8		0.8	V	
VI	Input voltage	0	5.5	0	5.5	V	
Vo	Output voltage	0	VCC	0	VCC	V	
ІОН	High-level output current		-8		-8	mA	
loL	Low-level output current		8		8	mA	
Δt/Δν	Input transition rise or fall rate		20		20	ns/V	
TA	Operating free-air temperature	- 55	125	-40	85	°C	

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T _{V==}	T,	λ = 25°C	;	SN54AH	CT573	SN74AHCT573		UNIT
PARAMETER	TEST CONDITIONS	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
Vari	I _{OH} = -50 μA	4.5 V	4.4	4.5		4.4		4.4		V
VOH	I _{OH} = -8 mA	7 4.5 V	3.94			3.8		3.8		
Voi	$I_{OL} = 50 \mu A$	4.5 V			0.1		0.1		0.1	V
VOL	I _{OL} = 8 mA				0.36		0.44		0.44	V
lį	$V_I = V_{CC}$ or GND	5.5 V			±0.1		±1		±1	μΑ
loz	$V_O = V_{CC}$ or GND	5.5 V			±0.25		±2.5		±2.5	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40		40	μΑ
∆l _{CC} †	One input at 3.4 V, Other inputs at V _{CC} or GND	5.5 V			1.35		1.5		1.5	mA
C _i	V _I = V _{CC} or GND	5 V		2.5	10				10	pF
Co	$V_O = V_{CC}$ or GND	5 V		3						pF

[†] This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

timing requirements over recommended operating free-air temperature range, $\rm V_{CC}$ = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

		T _A = 25°C		SN54AHCT573		SN74AHCT573		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	ONIT
t _W	Pulse duration, LE high	5		5		5		ns
t _{su}	Setup time, data before LE↓	3.5		3.5		3.5		ns
th	Hold time, data after LE↓	1.5		1.5		1.5		ns



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switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	T _A = 25°C		SN54AH	CT573	SN74AH	CT573	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT	
t _{PLH}	D	Q	C _I = 15 pF		4.2*	6*	1*	6.5*	1	6.5	ns	
tPHL	D	ų ,	CL = 13 pr		5.1*	7*	1*	9*	1	9	115	
t _{PLH}	1 =	LE Q	C _L = 15 pF		4.7*	6.5*	1*	7.5*	1	7.5	ns	
tPHL	LC	Q	CL = 15 pr		5.6*	7.5*	1*	9*	1	9	115	
^t PZH	ŌĒ	Q	C 15 pE		4.1*	6.5*	1*	7*	1	7	ns	
tpzL] OE	Q	C _L = 15 pF		5.5*	7.5*	1*	10*	1	10	115	
tPHZ	OE Q		Q C _L = 15 pF		5.5*	8*	1*	11*	1	11	ns	
tPLZ	OE	ų ,			5.4*	8*	1*	9.5*	1	9.5		
t _{PLH}	D	Q	C: - 50 pF		5.2	7	1	7.5	1	7.5	ns	
tPHL		ų ,	C _L = 50 pF		6.1	8	1	10	1	10	115	
^t PLH	LE Q	0 0 50.5		5.7	7.5	1	8.5	1	8.5	ns		
t _{PHL}	LC	Q	C _L = 50 pF		6.6	8.5	1	10	1	10	115	
^t PZH		Q	C: - 50 pF		5.1	7.5	1	8	1	8	ns	
tPZL] OE	ŌĒ	Q	C _L = 50 pF		6.5	8.5	1	11	1	11	ns
t _{PHZ}	0 -	\overline{OF} Q $C_1 = 50 pF$		6.7	9	1	12	1	12	ns		
t _{PLZ}	ŌĒ	٧	$C_L = 50 \text{ pF}$		6.4	9	1	10.5	1	10.5	119	
t _{sk(o)}	·		C _L = 50 pF			1.5**				1.5	ns	

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

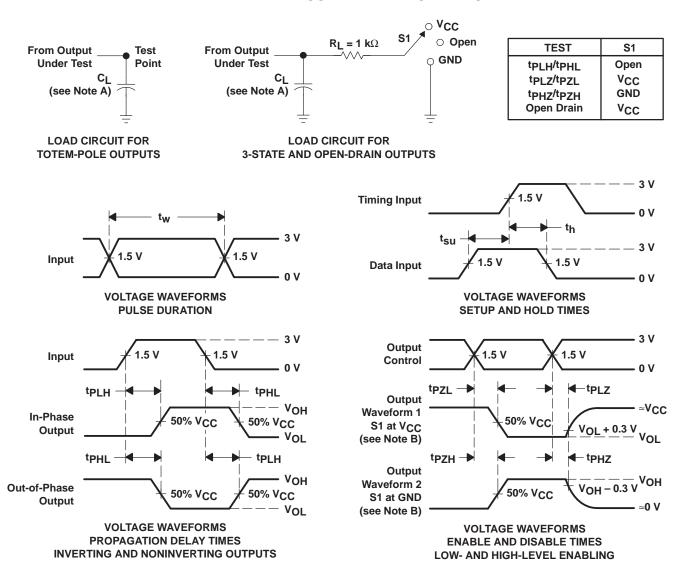
operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

	PARAMETER		ONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load,	f = 1 MHz	16	pF



^{**} On products compliant to MIL-PRF-38535, this parameter does not apply.

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \ \Omega$, $t_f \leq 3 \ ns$, $t_f \leq 3 \ ns$.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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